



JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD

## TO-92K Plastic-Encapsulate Thyristors

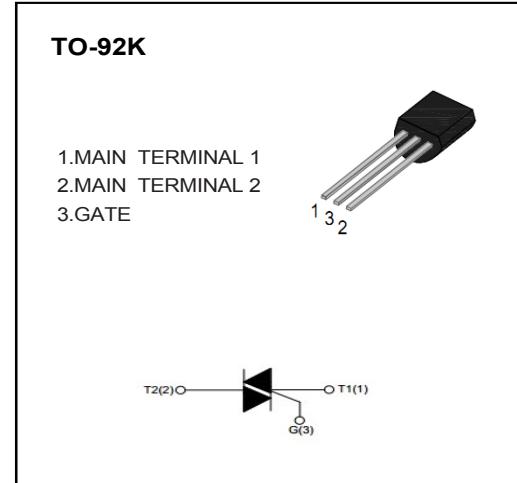
### CT401G 4Q TRIACs

#### MAIN CHARACTERISTICS

$I_{T(RMS)}$		1A
$V_{DRM}/V_{RRM}$	CT401G-600T/S	600V
	CT401G-800T/S	800V
$V_{TM}$		1.55V

#### FEATURES

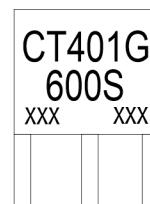
- NPNPN 5-layer Structure TRIACs
- Mesa Glass Passivated Technology
- Multi Layers Metal Electrodes
- High Junction Temperature
- Good Commutation Performance



#### APPLICATIONS

- Heater Control
- Motor Speed Controller
- Mixer

#### MARKING

CT401G:Series Code  
600S:Depends on  $V_{DRM}$ 

and IGT

XXX:Internal Code

#### ABSOLUTE RATINGS ( $T_a=25^\circ\text{C}$ unless otherwise noted )

Symbol	Parameter	Test condition		Value		Unit	
$V_{DRM}/ V_{RRM}$	Repetitive peak off-state voltage	$T_j=25^\circ\text{C}$	CT401G-600T/S	600		V	
			CT401G-800T/S	800		V	
$I_{T(RMS)}$	RMS on-state current	TO-92K( $T_c \leq 51^\circ\text{C}$ ), Fig. 1,2		1		A	
$I_{TSM}$	Non repetitive surge peak on-state current	Full sine wave , $T_j(\text{init})=25^\circ\text{C}$ , $tp=20\text{ms}$ ; Fig. 3,5		10		A	
$I^2t$	$I^2t$ value	$tp=10\text{ms}$		1.28		$\text{A}^2\text{s}$	
$dI_T/dt$	Critical rate of rise of on-state current	$I_G=2*I_{GT}$ , $tr \leq 10\text{ns}$ , $F=120\text{Hz}$ , $T_j=125^\circ\text{C}$	I - II - III	50	$\text{A}/\mu\text{s}$		
			IV	10			
$I_{GM}$	Peak gate current	$tp=20\mu\text{s}$ , $T_j=125^\circ\text{C}$		2		A	
$P_{G(AV)}$	Average gate power	$T_j=125^\circ\text{C}$		0.5		W	
$T_{STG}$	Storage temperature			$-40 \sim +150$		$^\circ\text{C}$	
$T_j$	Operating junction temperature			$-40 \sim +125$			

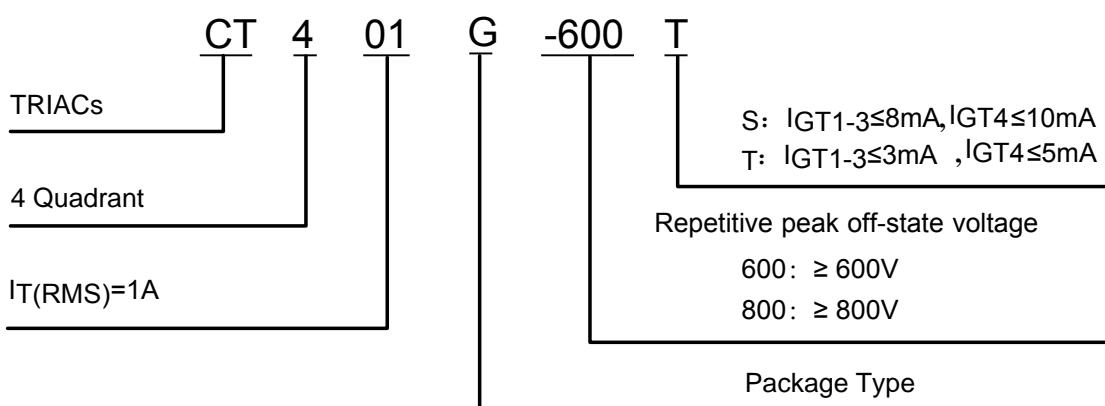
## ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test condition	Value		Unit
			T	S	
$I_{GT}$	Gate trigger current	$V_D=12\text{V}$ , $I_T=0.1\text{A}$ , $T_j=25^\circ\text{C}$ , Fig. 6	$\leq 3$	$\leq 8$	mA
			$\leq 5$	$\leq 10$	
$V_{GT}$	Gate trigger voltage	I - II - III - IV	$\leq 1.3$		V
$V_{GD}$	Non-triggering gate voltage	$V_D=V_{DRM}$ , $T_j=125^\circ\text{C}$	$\geq 0.2$		V
$I_H$	Holding current	$V_D=12\text{V}$ , $I_{GT}=0.1\text{A}$ , $T_j=25^\circ\text{C}$ , Fig. 6	$\leq 5$	$\leq 5$	mA
$I_L$	Latching current		$\leq 6$	$\leq 10$	mA
			$\leq 10$	$\leq 15$	mA
$dV_D/dt$	Critical rate of rise of off-state	$V_D=67\%V_{DRM}$ , Gate Open $T_j=125^\circ\text{C}$	$\geq 20$	$\geq 50$	V/ $\mu\text{s}$
$V_{TM}$	On-state Voltage	$I_{TM}=1.5\text{A}$ , $t_p=380\mu\text{s}$ , Fig. 4	$\leq 1.55$		V
$I_{DRM} / I_{RRM}$	Repetitive peak off-state current	$V_D=V_{DRM}/V_{RRM}$ , $T_j=25^\circ\text{C}$	$\leq 5$	$\leq 5$	$\mu\text{A}$
		$V_D=V_{DRM}/V_{RRM}$ , $T_j=125^\circ\text{C}$	$\leq 0.1$	$\leq 0.1$	mA

## THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th} (j-c)$	Junction to case (AC)	60	$^\circ\text{C/W}$
$R_{th} (j-a)$	Junction to ambient	150	$^\circ\text{C/W}$

## PART NUMBER



## CHARACTERISTICS CURVES

FIG.1: Maximum power dissipation versus RMS on-state current (full cycle)

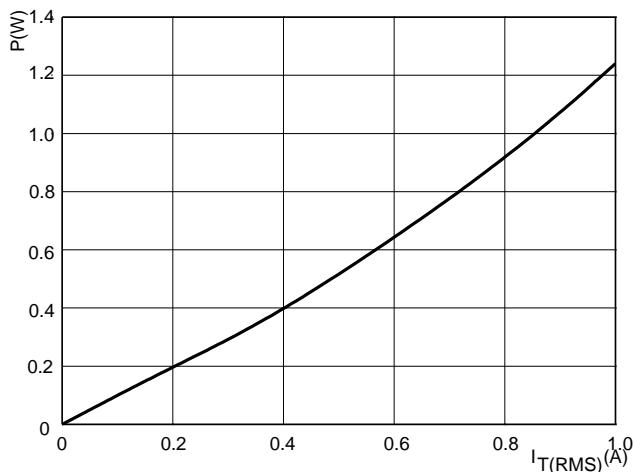


FIG.2: RMS on-state current versus case temperature (full cycle)

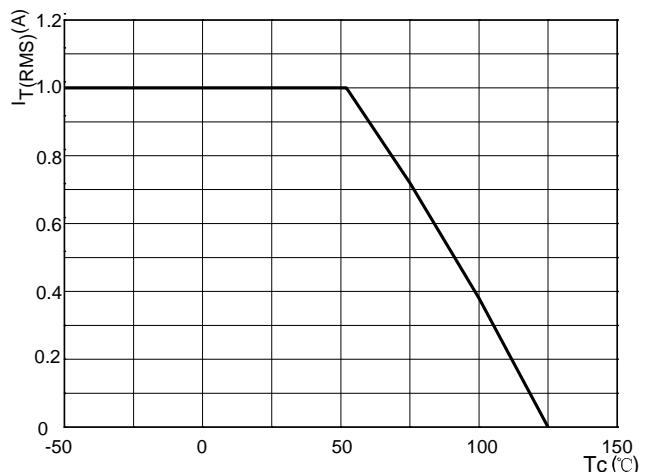


FIG.3: Surge peak on-state current versus number of cycles

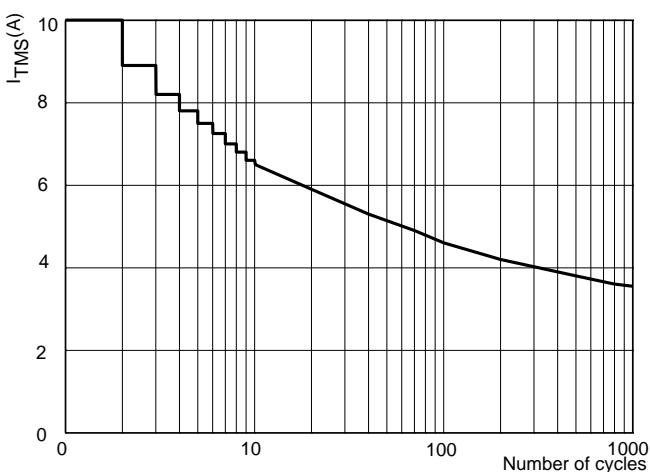


FIG.4: On-state characteristics (maximum values)

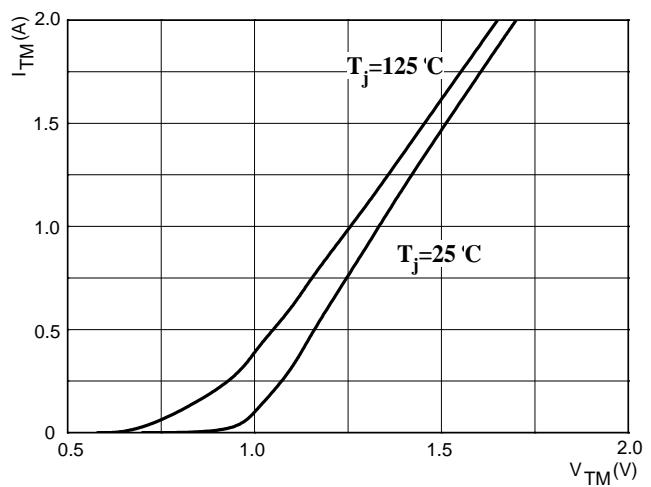


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10\text{ms}$

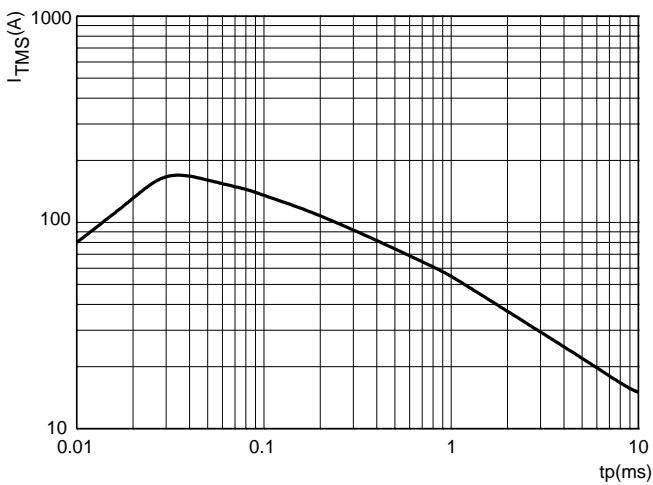
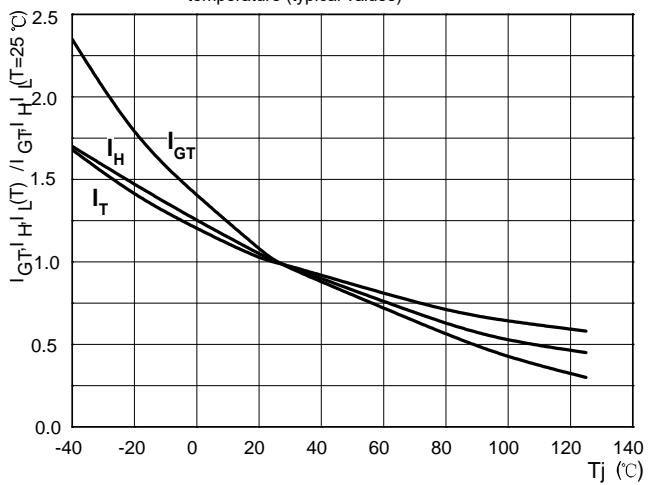
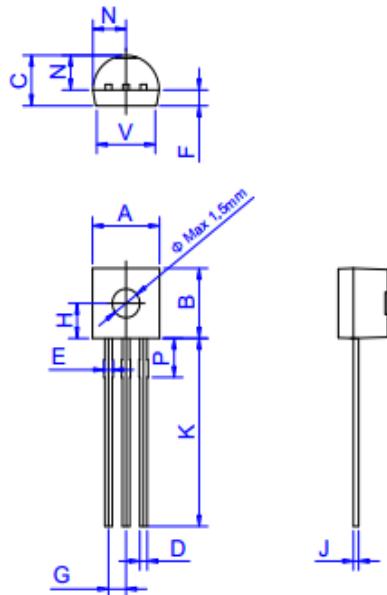


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature (typical values)



## TO-92K PACKAGE OUTLINE DIMENSIONS



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.45		5.20	0.175		0.205
B	4.32		5.33	0.170		0.210
C	3.18		4.19	0.125		0.165
D	0.407		0.533	0.016		0.021
E	0.60		0.80	0.024		0.031
F	-	1.1	-	-	0.043	-
G	-	1.27	-	-	0.050	-
H	-	2.30	-	-	0.091	-
J	0.36		0.50	0.014		0.020
K	12.70		15.0	0.500		0.591
N	2.04		2.66	0.080		0.105
P	1.86		2.06	0.073		0.081
V	-		4.3	-		0.169

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